Infineon Technologies - CY8C5666AXI-LP001 Datasheet

Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	67MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	CapSense, DMA, LCD, POR, PWM, WDT
Number of I/O	62
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 2x12b; D/A 4x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c5666axi-lp001

very low power internal low-speed oscillator (ILO) for the sleep and watchdog timers. A 32.768-kHz external watch crystal is also supported for use in RTC applications. The clocks, together with programmable clock dividers, provide the flexibility to integrate most timing requirements.

The CY8C56LP family supports a wide supply operating range from 1.71 to 5.5 V. This allows operation from regulated supplies such as 1.8 ± 5%, 2.5 V ±10%, 3.3 V ± 10%, or 5.0 V ± 10%, or directly from a wide range of battery types. In addition, it provides an integrated high efficiency synchronous boost converter that can power the device from supply voltages as low as 0.5 V. This enables the device to be powered directly from a single battery. In addition, you can use the boost converter to generate other voltages required by the device, such as a 3.3 V supply for LCD glass drive. The boost's output is available on the VBOOST pin, allowing other devices in the application to be powered from the PSoC.

PSoC supports a wide range of low power modes. These include a 300 nA hibernate mode with RAM retention and a 2 µA sleep mode with RTC. In the second mode the optional 32.768-kHz watch crystal runs continuously and maintains an accurate RTC.

Power to all major functional blocks, including the programmable digital and analog peripherals, can be controlled independently by firmware. This allows low power background processing when some peripherals are not in use. This, in turn, provides a total device current of only 3.1 mA when the CPU is running at 6 MHz.

The details of the PSoC power modes are covered in the "Power System" section on page 26 of this datasheet.

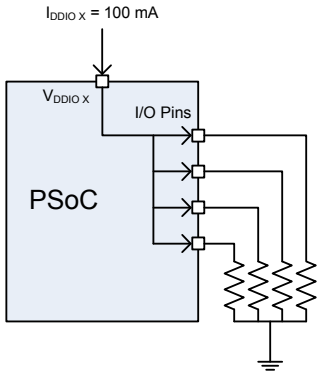
PSoC uses JTAG (4 wire) or SWD (2 wire) interfaces for programming, debug, and test. Using these standard interfaces you can debug or program the PSoC with a variety of hardware solutions from Cypress or third party vendors. The Cortex-M3 debug and trace modules include Flash Patch and Breakpoint (FPB), Data Watchpoint and Trace (DWT), Embedded Trace Macrocell (ETM), and Instrumentation Trace Macrocell (ITM). These modules have many features to help solve difficult debug and trace problems. Details of the programming, test, and debugging interfaces are discussed in the "Programming, Debug Interfaces, Resources" section on page 61 of this datasheet.

2. Pinouts

Each VDDIO pin powers a specific set of I/O pins. (The USBIOs are powered from VDDD.) Using the VDDIO pins, a single PSoC can support multiple voltage levels, reducing the need for off-chip level shifters. The black lines drawn on the pinout diagrams in Figure 2-3 and Figure 2-4, as well as Table 2-1, show the pins that are powered by each VDDIO.

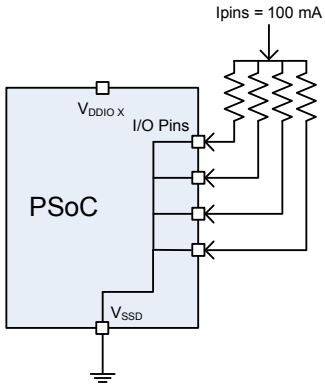
Each VDDIO may source up to 100 mA total to its associated I/O pins, as shown in Figure 2-1.

Figure 2-1. VDDIO Current Limit



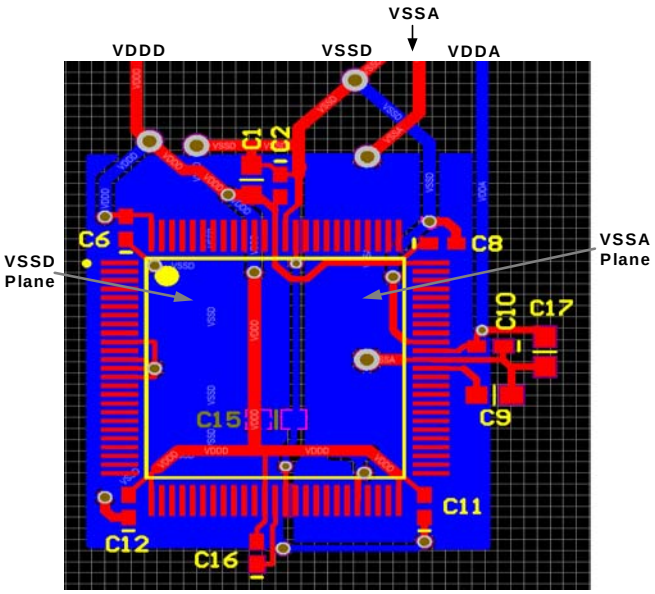
Conversely, for the 100-pin and 68-pin devices, the set of I/O pins associated with any VDDIO may sink up to 100 mA total, as shown in Figure 2-2.

Figure 2-2. I/O Pins Current Limit



Note
3. Pins are Do Not Use (DNU) on devices without USB. The pin must be left floating.

Figure 2-6. Example PCB Layout for 100-pin TQFP Part for Optimal Analog Performance



3. Pin Descriptions

IDAC0, IDAC1, IDAC2, IDAC3

Low resistance output pin for high current DACs (IDAC).

Opamp0out, Opamp1out, Opamp2out, Opamp3out

High current output of uncommitted opamp[7].

Extref0, Extref1

External reference input to the analog system.

SAR0 EXTREF, SAR1 EXTREF

External references for SAR ADCs

Opamp0–, Opamp1–, Opamp2–, Opamp3–

Inverting input to uncommitted opamp.

Opamp0+, Opamp1+, Opamp2+, Opamp3+

Noninverting input to uncommitted opamp.

GPIO

General purpose I/O pin provides interfaces to the CPU, digital peripherals, analog peripherals, interrupts, LCD segment drive, and CapSense[7].

I2C0: SCL, I2C1: SCL

I^2C SCL line providing wake from sleep on an address match. Any I/O pin can be used for I^2C SCL if wake from sleep is not required.

I2C0: SDA, I2C1: SDA

I^2C SDA line providing wake from sleep on an address match. Any I/O pin can be used for I^2C SDA if wake from sleep is not required.

Ind

Inductor connection to boost pump.

kHz XTAL: Xo, kHz XTAL: Xi

32.768-kHz crystal oscillator pin.

MHz XTAL: Xo, MHz XTAL: Xi

4 to 25 MHz crystal oscillator pin.

nTRST

Optional JTAG Test Reset programming and debug port connection to reset the JTAG connection.

SIO. Special I/O provides interfaces to the CPU, digital peripherals and interrupts with a programmable high threshold voltage, analog comparator, high sink current, and high impedance state when the device is unpowered.

SWDCK

Serial Wire Debug Clock programming and debug port connection.

SWDIO

Serial Wire Debug Input and Output programming and debug port connection.

TCK

JTAG Test Clock programming and debug port connection.

TDI

JTAG Test Data In programming and debug port connection.

TDO

JTAG Test Data Out programming and debug port connection.

TMS

JTAG Test Mode Select programming and debug port connection.

TRACECLK

Cortex-M3 TRACEPORT connection, clocks TRACEDATA pins.

TRACEDATA[3:0].

Cortex-M3 TRACEPORT connections, output data.

SWV.

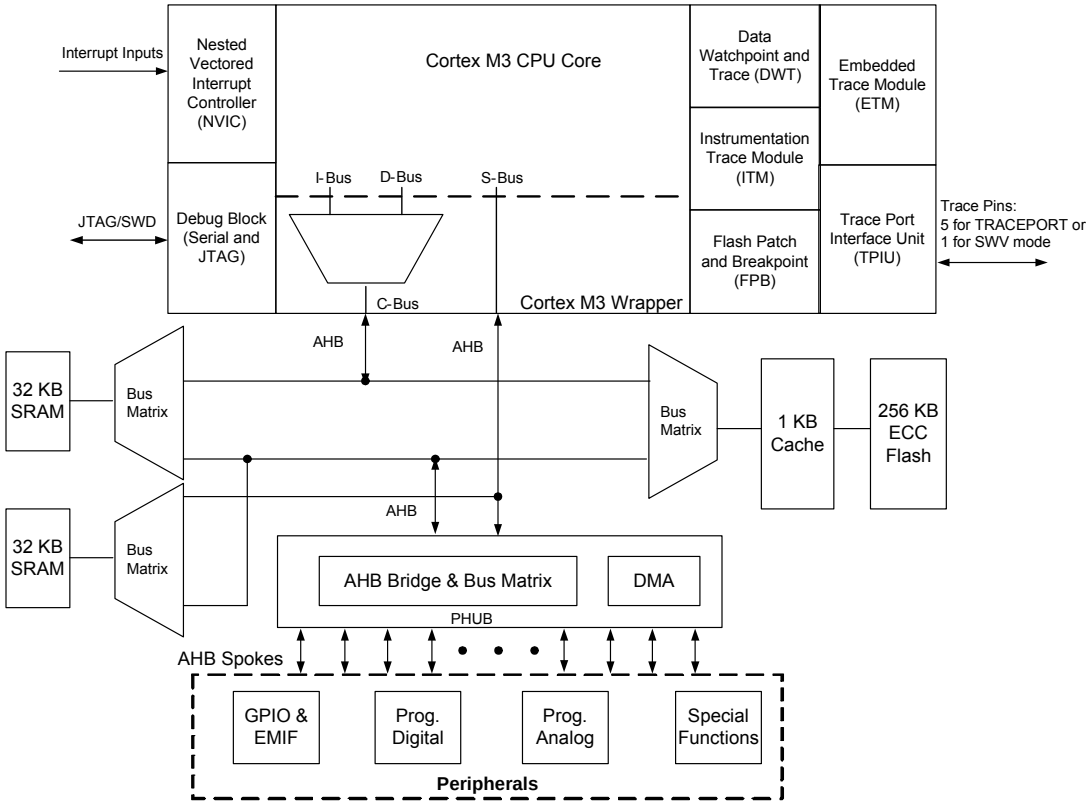
Single Wire Viewer output.

USBIO, D+

Provides D+ connection directly to a USB 2.0 bus. May be used as a digital I/O pin; it is powered from VDDD instead of from a VDDIO. Pins are Do Not Use (DNU) on devices without USB.

Note
7. GPIOs with opamp outputs are not recommended for use with CapSense.

Figure 4-1. ARM Cortex-M3 Block Diagram



The Cortex-M3 CPU subsystem includes these features:

- ARM Cortex-M3 CPU
- Programmable Nested Vectored Interrupt Controller (NVIC), tightly integrated with the CPU core
- Full featured debug and trace modules, tightly integrated with the CPU core
- Up to 256 KB of flash memory, 2 KB of EEPROM, and 64 KB of SRAM
- Cache controller
- Peripheral HUB (PHUB)
- DMA controller
- External Memory Interface (EMIF)

4.1.1 Cortex-M3 Features

The Cortex-M3 CPU features include:

- 4 GB address space. Predefined address regions for code, data, and peripherals. Multiple buses for efficient and simultaneous accesses of instructions, data, and peripherals.
- The Thumb®-2 instruction set, which offers ARM-level performance at Thumb-level code density. This includes 16-bit and 32-bit instructions. Advanced instructions include:
  - Bit-field control
  - Hardware multiply and divide
  - Saturation
  - If-Then
  - Wait for events and interrupts
  - Exclusive access and barrier
  - Special register access

  The Cortex-M3 does not support ARM instructions.
- Bit-band support for the SRAM region. Atomic bit-level write and read operations for SRAM addresses.
- Unaligned data storage and access. Contiguous storage of data of different byte lengths.
- Operation at two privilege levels (privileged and user) and in two modes (thread and handler). Some instructions can only be executed at the privileged level. There are also two stack pointers: Main (MSP) and Process (PSP). These features support a multitasking operating system running one or more user-level processes.
- Extensive interrupt and system exception support.

6. System Integration

6.1 Clocking System

The clocking system generates, divides, and distributes clocks throughout the PSoC system. For the majority of systems, no external crystal is required. The IMO and PLL together can generate up to a 80 MHz clock, accurate to ±1% over voltage and temperature. Additional internal and external clock sources allow each design to optimize accuracy, power, and cost. All of the system clock sources can be used to generate other clock frequencies in the 16-bit clock dividers and UDBs for anything the user wants, for example a UART baud rate generator.

Clock generation and distribution is automatically configured through the PSoC Creator IDE graphical interface. This is based on the complete system's requirements. It greatly speeds the design process. PSoC Creator allows designers to build clocking systems with minimal input. The designer can specify desired clock frequencies and accuracies, and the software locates or builds a clock that meets the required specifications. This is possible because of the programmability inherent in PSoC.

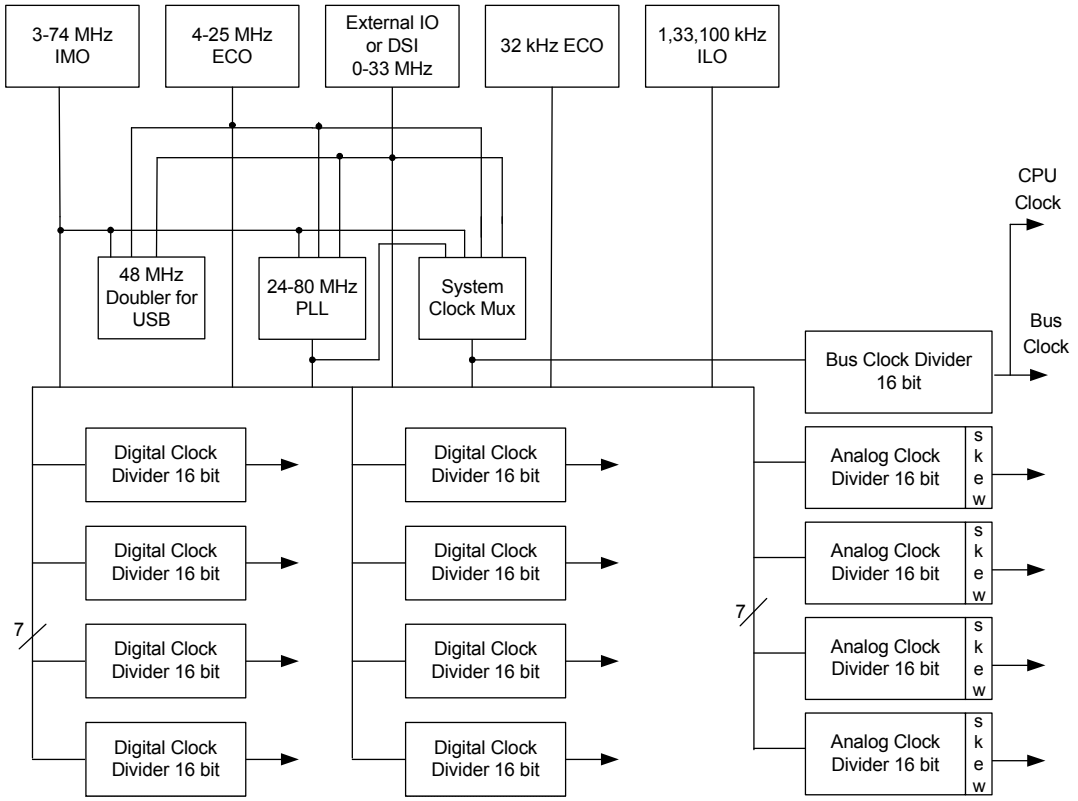
Key features of the clocking system include:

- Seven general purpose clock sources
  - 3- to 74-MHz IMO, ±1% at 3 MHz
  - 4- to 25-MHz External Crystal Oscillator (MHzECO)
  - Clock doubler provides a doubled clock frequency output for the USB block, see USB Clock Domain on page 26
  - DSI signal from an external I/O pin or other logic
  - 24- to 80-MHz fractional Phase-Locked Loop (PLL) sourced from IMO, MHzECO, or DSI
  - Clock Doubler
  - 1-kHz, 33-kHz, 100-kHz ILO for Watch Dog Timer (WDT) and Sleep Timer
  - 32.768-kHz External Crystal Oscillator (kHzECO) for Real Time Clock (RTC)
- IMO has a USB mode that auto locks to USB bus clock requiring no external crystal for USB. (USB equipped parts only)
- Independently sourced clock in all clock dividers
- Eight 16-bit clock dividers for the digital system
- Four 16-bit clock dividers for the analog system
- Dedicated 16-bit divider for the CPU bus and CPU clock
- Automatic clock configuration in PSoC Creator

Table 6-1. Oscillator Summary

Source	Fmin	Tolerance at Fmin	Fmax	Tolerance at Fmax	Startup Time
IMO	3 MHz	±1% over voltage and temperature	74 MHz	±7%	13 µs max
MHzECO	4 MHz	Crystal dependent	25 MHz	Crystal dependent	5 ms typ, max is crystal dependent
DSI	0 MHz	Input dependent	33 MHz	Input dependent	Input dependent
PLL	24 MHz	Input dependent	80 MHz	Input dependent	250 µs max
Doubler	12 MHz	Input dependent	48 MHz	Input dependent	1 µs max
ILO	1 kHz	–50%, +100%	100 kHz	–55%, +100%	15 ms max in lowest power mode
kHzECO	32 kHz	Crystal dependent	32 kHz	Crystal dependent	500 ms typ, max is crystal dependent

Figure 6-1. Clocking Subsystem



6.1.1 Internal Oscillators

Figure 6-1 shows that there are two internal oscillators. They can be routed directly or divided. The direct routes may not have a 50% duty cycle. Divided clocks have a 50% duty cycle.

6.1.1.1 Internal Main Oscillator

In most designs the IMO is the only clock source required, due to its ±1% accuracy. The IMO operates with no external components and outputs a stable clock. A factory trim for each frequency range is stored in the device. With the factory trim, tolerance varies from ±1% at 3 MHz, up to ±7% at 74 MHz. The IMO, in conjunction with the PLL, allows generation of CPU and system clocks up to the device's maximum frequency (see Phase-Locked Loop)

The IMO provides clock outputs at 3, 6, 12, 24, 48, and 74 MHz.

6.1.1.2 Clock Doubler

The clock doubler outputs a clock at twice the frequency of the input clock. The doubler works for input frequency ranges of 6 to 24 MHz (providing 12 to 48 MHz at the output). It can be configured to use a clock from the IMO, MHzECO, or the DSI (external pin). The doubler is typically used to clock the USB.

6.1.1.3 Phase-Locked Loop

The PLL allows low frequency, high accuracy clocks to be multiplied to higher frequencies. This is a tradeoff between higher clock frequency and accuracy and, higher power consumption and increased startup time.

The PLL block provides a mechanism for generating clock frequencies based upon a variety of input sources. The PLL outputs clock frequencies in the range of 24 to 80 MHz. Its input and feedback dividers supply 4032 discrete ratios to create almost any desired system clock frequency. The accuracy of the PLL output depends on the accuracy of the PLL input source. The most common PLL use is to multiply the IMO clock at 3 MHz, where it is most accurate, to generate the CPU and system clocks up to the device's maximum frequency.

The PLL achieves phase lock within 250 µs (verified by bit setting). It can be configured to use a clock from the IMO, MHzECO or DSI (external pin). The PLL clock source can be used until lock is complete and signaled with a lock bit. The lock signal can be routed through the DSI to generate an interrupt. Disable the PLL before entering low power modes.

6.1.1.4 Internal Low Speed Oscillator

The ILO provides clock frequencies for low power consumption, including the watchdog timer, and sleep timer. The ILO generates up to three different clocks: 1 kHz, 33 kHz, and 100 kHz.

The 1 kHz clock (CLK1K) is typically used for a background 'heartbeat' timer. This clock inherently lends itself to low power supervisory operations such as the watchdog timer and long sleep intervals using the central timewheel (CTW).

The central timewheel is a 1 kHz, free running, 13-bit counter clocked by the ILO. The central timewheel is always enabled except in hibernate mode and when the CPU is stopped during debug on chip mode. It can be used to generate periodic interrupts for timing purposes or to wake the system from a low power mode. Firmware can reset the central timewheel.

The central timewheel can be programmed to wake the system periodically and optionally issue an interrupt. This enables flexible, periodic wakeups from low power modes or coarse timing applications. Systems that require accurate timing should use Real Time Clock capability instead of the central timewheel.

The 100-kHz clock (CLK100K) can be used as a low power system clock to run the CPU. It can also generate time intervals using the fast timewheel.

The fast timewheel is a 5-bit counter, clocked by the 100-kHz clock. It features programmable settings and automatically resets when the terminal count is reached. An optional interrupt can be generated each time the terminal count is reached. This enables flexible, periodic interrupts of the CPU at a higher rate than is allowed using the central timewheel.

The 33 kHz clock (CLK33K) comes from a divide-by-3 operation on CLK100K. This output can be used as a reduced accuracy version of the 32.768 kHz ECO clock with no need for a crystal.

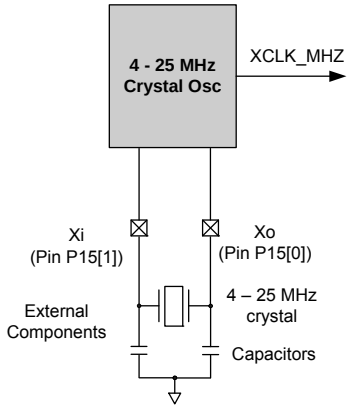
6.1.2 External Oscillators

Figure 6-1 shows that there are two external oscillators. They can be routed directly or divided. The direct routes may not have a 50% duty cycle. Divided clocks have a 50% duty cycle.

6.1.2.1 MHz External Crystal Oscillator

The MHzECO provides high frequency, high precision clocking using an external crystal (see Figure 6-2). It supports a wide variety of crystal types, in the range of 4 to 25 MHz. When used in conjunction with the PLL, it can generate CPU and system clocks up to the device's maximum frequency (see Phase-Locked Loop on page 24). The GPIO pins connecting to the external crystal and capacitors are fixed. MHzECO accuracy depends on the crystal chosen.

Figure 6-2. MHzECO Block Diagram

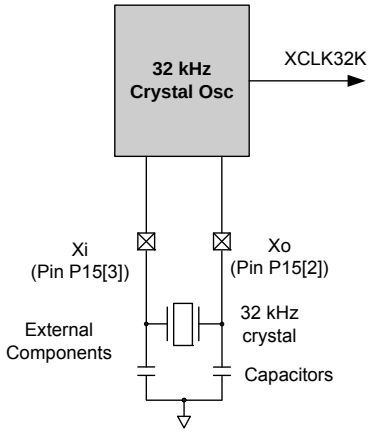


6.1.2.2 32.768 kHz ECO

The 32.768 kHz External Crystal Oscillator (32kHzECO) provides precision timing with minimal power consumption using an external 32.768 kHz watch crystal (see Figure 6-3). The 32kHzECO also connects directly to the sleep timer and provides the source for the Real Time Clock (RTC). The RTC uses a 1 second interrupt to implement the RTC functionality in firmware.

The oscillator works in two distinct power modes. This allows users to trade off power consumption with noise immunity from neighboring circuits. The GPIO pins connected to the external crystal and capacitors are fixed.

Figure 6-3. 32kHzECO Block Diagram



It is recommended that the external 32.768-kHz watch crystal have a load capacitance (CL) of 6 pF or 12.5 pF. Check the crystal manufacturer's datasheet. The two external capacitors, CL1 and CL2, are typically of the same value, and their total capacitance, CL1CL2 / (CL1 + CL2), including pin and trace capacitance, should equal the crystal CL value. For more information, refer to application note AN54439: PSoC 3 and PSoC 5 External Oscillators. See also pin capacitance specifications in the “GPIO” section on page 75.

6.1.2.3 Digital System Interconnect

The DSI provides routing for clocks taken from external clock oscillators connected to I/O. The oscillators can also be generated within the device in the digital system and UDBs.

While the primary DSI clock input provides access to all clocking resources, up to eight other DSI clocks (internally or externally generated) may be routed directly to the eight digital clock dividers. This is only possible if there are multiple precision clock sources.

6.1.3 Clock Distribution

All seven clock sources are inputs to the central clock distribution system. The distribution system is designed to create multiple high precision clocks. These clocks are customized for the design’s requirements and eliminate the common problems found with limited resolution prescalers attached to peripherals. The clock distribution system generates several types of clock trees.

- The system clock is used to select and supply the fastest clock in the system for general system clock requirements and clock synchronization of the PSoC device.
- Bus Clock 16-bit divider uses the system clock to generate the system’s bus clock used for data transfers and the CPU. The CPU clock is directly derived from the bus clock.
- Eight fully programmable 16-bit clock dividers generate digital system clocks for general use in the digital system, as configured by the design’s requirements. Digital system clocks can generate custom clocks derived from any of the seven clock sources for any purpose. Examples include baud rate generators, accurate PWM periods, and timer clocks, and many others. If more than eight digital clock dividers are required, the UDBs and fixed function Timer/Counter/PWMs can also generate clocks.

- Four 16-bit clock dividers generate clocks for the analog system components that require clocking, such as ADCs and mixers. The analog clock dividers include skew control to ensure that critical analog events do not occur simultaneously with digital switching events. This is done to reduce analog system noise.

Each clock divider consists of an 8-input multiplexer, a 16-bit clock divider (divide by 2 and higher) that generates ~50% duty cycle clocks, system clock resynchronization logic, and deglitch logic. The outputs from each digital clock tree can be routed into the digital system interconnect and then brought back into the clock system as an input, allowing clock chaining of up to 32 bits.

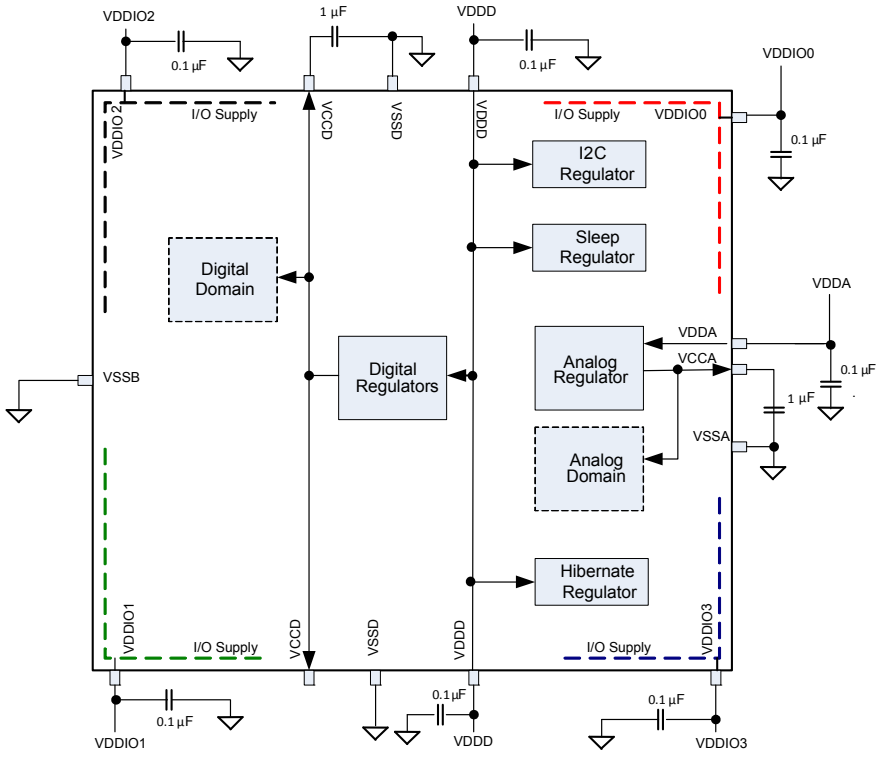
6.1.4 USB Clock Domain

The USB clock domain is unique in that it operates largely asynchronously from the main clock network. The USB logic contains a synchronous bus interface to the chip, while running on an asynchronous clock to process USB data. The USB logic requires a 48 MHz frequency. This frequency can be generated from different sources, including DSI clock at 48 MHz or doubled value of 24 MHz from internal oscillator, DSI signal, or crystal oscillator.

6.2 Power System

The power system consists of separate analog, digital, and I/O supply pins, labeled VDDA, VDDD, and VDDIOX, respectively. It also includes two internal 1.8 V regulators that provide the digital (VCCD) and analog (VCCA) supplies for the internal core logic. The output pins of the regulators (VCCD and VCCA) and the VDDIO pins must have capacitors connected as shown in Figure 6-4. The two VCCD pins must be shorted together, with as short a trace as possible, and connected to a 1 µF ±10% X5R capacitor. The power system also contains a sleep regulator, an I^2C regulator, and a hibernate regulator.

Figure 6-4. PSoC Power System



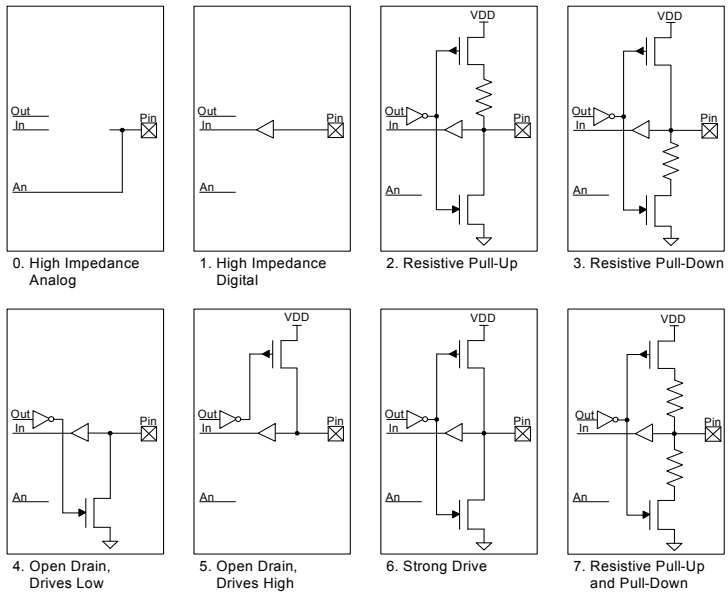
Notes

- The two V_{CCD} pins must be connected together with as short a trace as possible. A trace under the device is recommended, as shown in Figure 2-6.
- You can power the device in internally regulated mode, where the voltage applied to the V_{DDx} pins is as high as 5.5 V, and the internal regulators provide the core voltages. **In this mode, do not apply power to the V_{CCx} pins, and do not tie the V_{DDx} pins to the V_{CCx} pins.**
- You can also power the device in externally regulated mode, that is, by directly powering the V_{CCD} and V_{CCA} pins. In this configuration, the V_{DDD} pins should be shorted to the V_{CCD} pins and the V_{DDA} pin should be shorted to the V_{CCA} pin. The allowed supply range in this configuration is 1.71 V to 1.89 V. After power up in this configuration, the internal regulators are on by default, and should be disabled to reduce power consumption.
- It is good practice to check the datasheets for your bypass capacitors, specifically the working voltage and the DC bias specifications. With some capacitors, the actual capacitance can decrease considerably when the DC bias (V_{DDX} or V_{CCX} in Figure 6-4) is a significant percentage of the rated working voltage.

6.4.1 Drive Modes

Each GPIO and SIO pin is individually configurable into one of the eight drive modes listed in Table 6-6. Three configuration bits are used for each pin (DM[2:0]) and set in the PRTxDM[2:0] registers. Figure 6-12 depicts a simplified pin view based on each of the eight drive modes. Table 6-6 shows the I/O pin's drive state based on the port data register value or digital array signal if bypass mode is selected. Note that the actual I/O pin voltage is determined by a combination of the selected drive mode and the load at the pin. For example, if a GPIO pin is configured for resistive pull up mode and driven high while the pin is floating, the voltage measured at the pin is a high logic state. If the same GPIO pin is externally tied to ground then the voltage unmeasured at the pin is a low logic state.

Figure 6-12. Drive Mode



The 'Out' connection is driven from either the Digital System (when the Digital Output terminal is connected) or the Data Register (when HW connection is disabled).
The 'In' connection drives the Pin State register, and the Digital System if the Digital Input terminal is enabled and connected.
The 'An' connection connects to the Analog System.

Table 6-6. Drive Modes

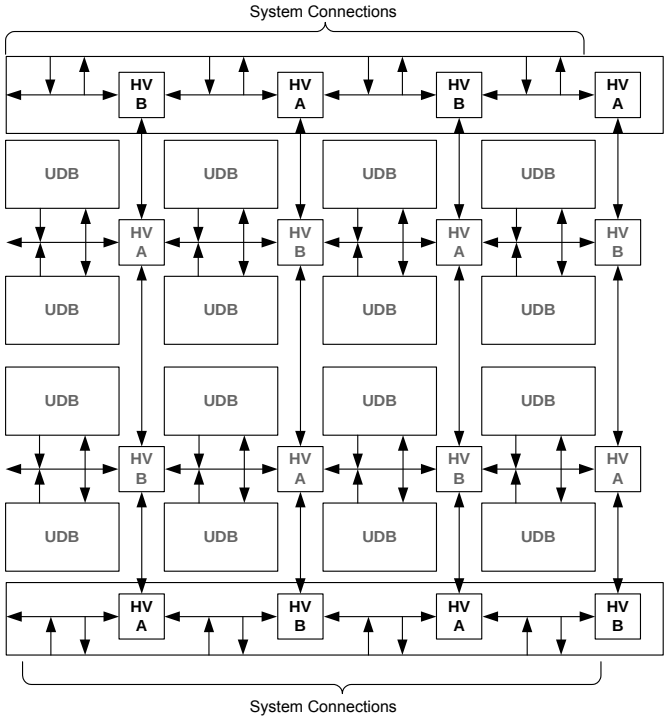
Diagram	Drive Mode	PRTxDM2	PRTxDM1	PRTxDM0	PRTxDR = 1	PRTxDR = 0
0	High-impedance analog	0	0	0	High Z	High Z
1	High-impedance digital	0	0	1	High Z	High Z
2	Resistive pull-up[10]	0	1	0	Res High (5K)	Strong Low
3	Resistive pull-down[10]	0	1	1	Strong High	Res Low (5K)
4	Open drain, drives low	1	0	0	High Z	Strong Low
5	Open drain, drive high	1	0	1	Strong High	High Z
6	Strong drive	1	1	0	Strong High	Strong Low
7	Resistive pull up and pull down[10]	1	1	1	Res High (5K)	Res Low (5K)

Note
10. Resistive pull up and pull down are not available with SIO in regulated output mode.

7.3 UDB Array Description

Figure 7-7 shows an example of a 16 UDB array. In addition to the array core, there are a DSI routing interfaces at the top and bottom of the array. Other interfaces that are not explicitly shown include the system interfaces for bus and clock distribution. The UDB array includes multiple horizontal and vertical routing channels each comprised of 96 wires. The wire connections to UDBs, at horizontal/vertical intersection and at the DSI interface are highly permutable providing efficient automatic routing in PSoC Creator. Additionally the routing allows wire by wire segmentation along the vertical and horizontal routing to further increase routing flexibility and capability.

Figure 7-7. Digital System Interface Structure

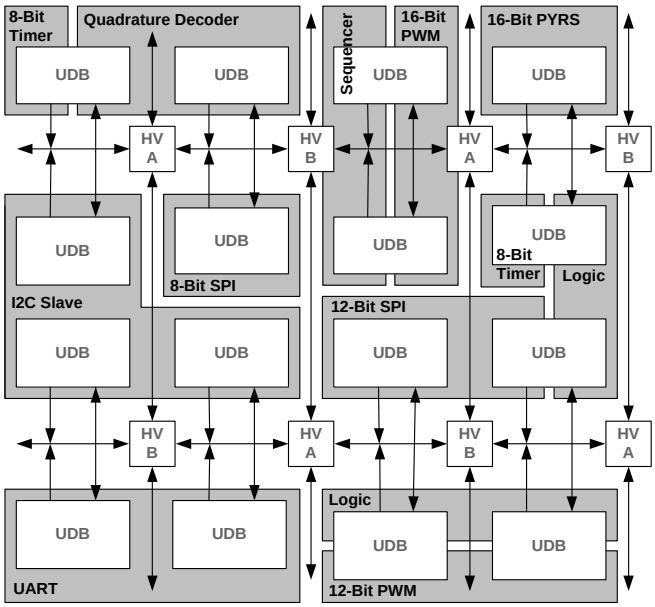


7.3.1 UDB Array Programmable Resources

Figure 7-8 shows an example of how functions are mapped into a bank of 16 UDBs. The primary programmable resources of the UDB are two PLDs, one datapath and one status/control register. These resources are allocated independently, because they have independently selectable clocks, and therefore unused blocks are allocated to other unrelated functions.

An example of this is the 8-bit Timer in the upper left corner of the array. This function only requires one datapath in the UDB, and therefore the PLD resources may be allocated to another function. A function such as a Quadrature Decoder may require more PLD logic than one UDB can supply and in this case can utilize the unused PLD blocks in the 8-bit Timer UDB. Programmable resources in the UDB array are generally homogeneous so functions can be mapped to arbitrary boundaries in the array.

Figure 7-8. Function Mapping Example in a Bank of UDBs



7.4 DSI Routing Interface Description

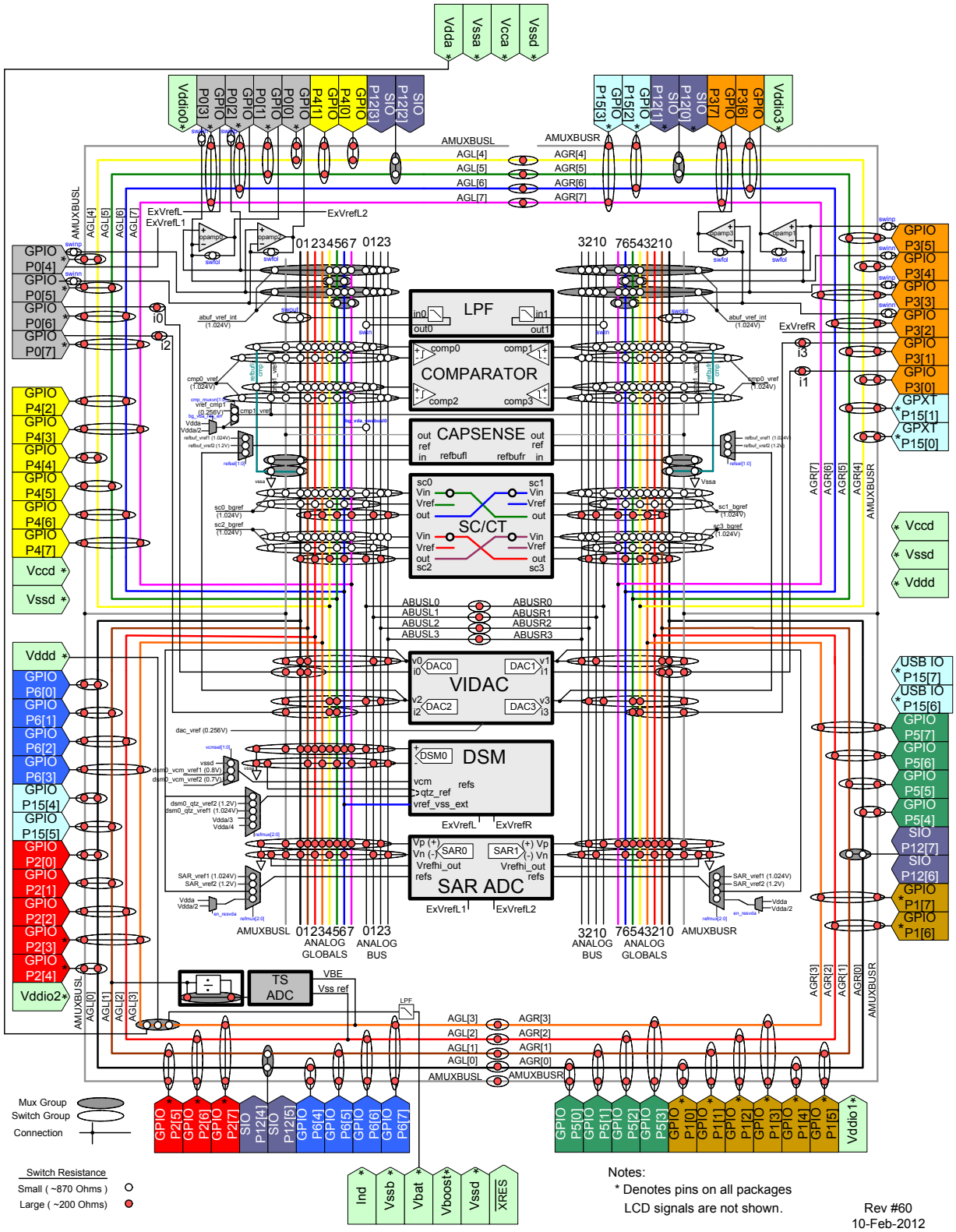
The DSI routing interface is a continuation of the horizontal and vertical routing channels at the top and bottom of the UDB array core. It provides general purpose programmable routing between device peripherals, including UDBs, I/Os, analog peripherals, interrupts, DMA and fixed function peripherals.

Figure 7-9 illustrates the concept of the digital system interconnect, which connects the UDB array routing matrix with other device peripherals. Any digital core or fixed function peripheral that needs programmable routing is connected to this interface.

Signals in this category include:

- Interrupt requests from all digital peripherals in the system.
- DMA requests from all digital peripherals in the system.
- Digital peripheral data signals that need flexible routing to I/Os.
- Digital peripheral data signals that need connections to UDBs.
- Connections to the interrupt and DMA controllers.
- Connection to I/O pins.
- Connection to analog system digital signals.

Figure 8-2. CY8C56LP Analog Interconnect



To preserve detail of this image, this image is best viewed with a PDF display program or printed on 11” × 17” paper.

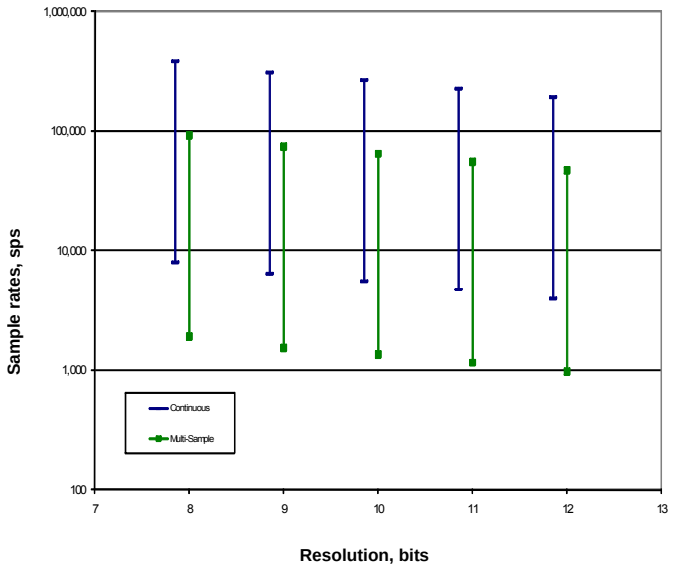
8.2 Delta-sigma ADC

Some CY8C36 devices offer a delta-sigma ADC. This ADC offers differential input, high resolution and excellent linearity, making it a good ADC choice for measurement applications. The converter can be configured to output 12-bit resolution at data rates of up to 192 ksps. At a fixed clock rate, resolution can be traded for faster data rates as shown in Table 8-1 and Figure 8-3.

Table 8-1. Delta-sigma ADC Performance

Bits	Maximum Sample Rate (sps)	SINAD (dB)
12	192 k	66
8	384 k	43

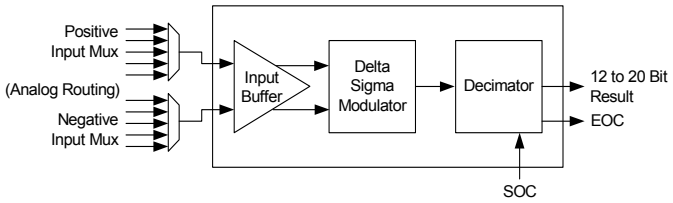
Figure 8-3. Delta-sigma ADC Sample Rates, Range = ±1.024 V



8.2.1 Functional Description

The ADC connects and configures three basic components, input buffer, delta-sigma modulator, and decimator. The basic block diagram is shown in Figure 8-4. The signal from the input muxes is delivered to the delta-sigma modulator either directly or through the input buffer. The delta-sigma modulator performs the actual analog to digital conversion. The modulator over-samples the input and generates a serial data stream output. This high speed data stream is not useful for most applications without some type of post processing, and so is passed to the decimator through the Analog Interface block. The decimator converts the high speed serial data stream into parallel ADC results. The modulator/decimator frequency response is $[(\sin x)/x]^4$.

Figure 8-4. Delta-sigma ADC Block Diagram



Resolution and sample rate are controlled by the Decimator. Data is pipelined in the decimator; the output is a function of the last four samples. When the input multiplexer is switched, the output data is not valid until after the fourth sample after the switch.

8.2.2 Operational Modes

The ADC can be configured by the user to operate in one of four modes: Single Sample, Multi Sample, Continuous, or Multi Sample (Turbo). All four modes are started by either a write to the start bit in a control register or an assertion of the Start of Conversion (SoC) signal. When the conversion is complete, a status bit is set and the output signal End of Conversion (EoC) asserts high and remains high until the value is read by either the DMA controller or the CPU.

8.2.2.1 Single Sample

In Single Sample mode, the ADC performs one sample conversion on a trigger. In this mode, the ADC stays in standby state waiting for the SoC signal to be asserted. When SoC is signaled the ADC performs four successive conversions. The first three conversions prime the decimator. The ADC result is valid and available after the fourth conversion, at which time the EoC signal is generated. To detect the end of conversion, the system may poll a control register for status or configure the external EoC signal to generate an interrupt or invoke a DMA request. When the transfer is done the ADC reenters the standby state where it stays until another SoC event.

8.2.2.2 Continuous

Continuous sample mode is used to take multiple successive samples of a single input signal. Multiplexing multiple inputs should not be done with this mode. There is a latency of three conversion times before the first conversion result is available. This is the time required to prime the decimator. After the first result, successive conversions are available at the selected sample rate.

8.2.2.3 Multi Sample

Multi sample mode is similar to continuous mode except that the ADC is reset between samples. This mode is useful when the input is switched between multiple signals. The decimator is re-primed between each sample so that previous samples do not affect the current conversion. Upon completion of a sample, the next sample is automatically initiated. The results can be transferred using either firmware polling, interrupt, or DMA.

More information on output formats is provided in the Technical Reference Manual.

Figure 11-11. Efficiency vs V_{BAT}, L_{BOOST} = 4.7 µH [33]

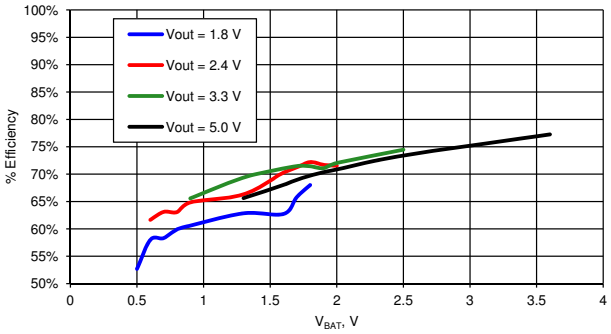


Figure 11-12. Efficiency vs V_{BAT}, L_{BOOST} = 10 µH [33]

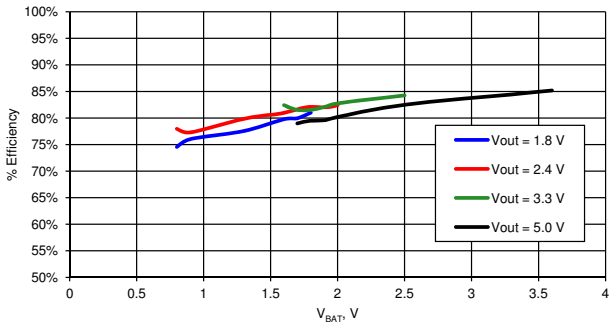


Figure 11-13. Efficiency vs V_{BAT}, L_{BOOST} = 22 µH [33]

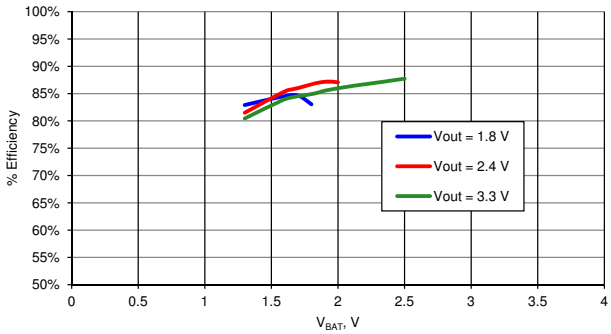
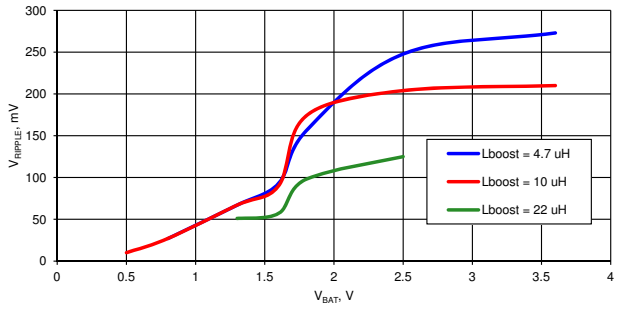


Figure 11-14. V_{RIPPLE} vs V_{BAT} [33]



Note
33. Typical example. Actual values may vary depending on external component selection, PCB layout, and other design parameters.

11.4.2 SIO

Table 11-10. SIO DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
Vinmax	Maximum input voltage	All allowed values of V_{DDIO} and V_{DDD}, see Section 11.1	–	–	5.5	V
Vinref	Input voltage reference (Differential input mode)		0.5	–	0.52 ×V_{DDIO}	V
Voutref	Output voltage reference (Regulated output mode)					
		V_{DDIO} > 3.7	1	–	V_{DDIO}–1	V
		V_{DDIO} < 3.7	1	–	V_{DDIO} – 0.5	V
V_{IH}	Input voltage high threshold					
	GPIO mode	CMOS input	0.7 × V_{DDIO}	–	–	V
	Differential input mode[37]	Hysteresis disabled	SIO_ref + 0.2	–	–	V
V_{IL}	Input voltage low threshold					
	GPIO mode	CMOS input	–	–	0.3 × V_{DDIO}	V
	Differential input mode[37]	Hysteresis disabled	–	–	SIO_ref – 0.2	V
V_{OH}	Output voltage high					
	Unregulated mode	I_{OH} = 4 mA, V_{DDIO} = 3.3 V	V_{DDIO} – 0.4	–	–	V
	Regulated mode[37]	I_{OH} = 1 mA	SIO_ref – 0.65	–	SIO_ref + 0.2	V
		I_{OH} = 0.1 mA	SIO_ref – 0.3	–	SIO_ref + 0.2	V
		no load, I_{OH} = 0	SIO_ref – 0.1	–	SIO_ref + 0.1	V
V_{OL}	Output voltage low	V_{DDIO} = 3.30 V, I_{OL} = 25 mA	–	–	0.8	V
		V_{DDIO} = 3.30 V, I_{OL} = 20 mA	–	–	0.4	V
		V_{DDIO} = 1.80 V, I_{OL} = 4 mA	–	–	0.4	V
Rpullup	Pull up resistor		3.5	5.6	8.5	kΩ
Rpulldown	Pull down resistor		3.5	5.6	8.5	kΩ
I_{IL}	Input leakage current (absolute value)[38]					
	$V_{IH} \le V_{DDSIO}$	25 °C, V_{DDSIO} = 3.0 V, V_{IH} = 3.0 V	–	–	14	nA
	$V_{IH} > V_{DDSIO}$	25 °C, V_{DDSIO} = 0 V, V_{IH} = 3.0 V	–	–	10	µA
C_{IN}	Input capacitance[38]		–	–	9	pF
V_H	Input voltage hysteresis (Schmitt–Trigger)[38]	Single ended mode (GPIO mode)	–	115	–	mV
		Differential mode	–	50	–	mV
Idiode	Current through protection diode to V_{SSIO}		–	–	100	µA

Notes
37. See Figure 6-10 on page 34 and Figure 6-13 on page 37 for more information on SIO reference.
38. Based on device characterization (Not production tested).

11.5.4 SAR ADC

Table 11-24. SAR ADC DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
	Resolution		–	–	12	bits
	Number of channels – single-ended		–	–	No of GPIO	
	Number of channels – differential	Differential pair is formed using a pair of neighboring GPIO.	–	–	No of GPIO/2	
	Monotonicity[47]		Yes	–	–	
Ge	Gain error[48]	External reference	–	–	±0.1	%
V_{OS}	Input offset voltage		–	–	±2	mV
I_{DD}	Current consumption[47]		–	–	1	mA
	Input voltage range – single-ended[47]		V_{SSA}	–	V_{DDA}	V
	Input voltage range – differential[47]		V_{SSA}	–	V_{DDA}	V
PSRR	Power supply rejection ratio[47]		70	–	–	dB
CMRR	Common mode rejection ratio		70	–	–	dB
INL	Integral non linearity[47]	V_{DDA} 1.71 to 5.5 V, 1 Msps, V_{REF} 1 to 5.5 V, bypassed at ExtRef pin	–	–	+2/–1.5	LSB
		V_{DDA} 2.0 to 3.6 V, 1 Msps, V_{REF} 2 to V_{DDA}, bypassed at ExtRef pin	–	–	±1.2	LSB
		V_{DDA} 1.71 to 5.5 V, 500 ksps, V_{REF} 1 to 5.5 V, bypassed at ExtRef pin	–	–	±1.3	LSB
DNL	Differential non linearity[47]	V_{DDA} 1.71 to 5.5 V, 1 Msps, V_{REF} 1 to 5.5 V, bypassed at ExtRef pin	–	–	+2/–1	LSB
		V_{DDA} 2.0 to 3.6 V, 1 Msps, V_{REF} 2 to V_{DDA}, bypassed at ExtRef pin No missing codes	–	–	1.7/–0.99	LSB
		V_{DDA} 1.71 to 5.5 V, 500 ksps, V_{REF} 1 to 5.5 V, bypassed at ExtRef pin No missing codes	–	–	+2/–0.99	LSB
R_{IN}	Input resistance[47]		–	180	–	kΩ

Notes
47. Based on device characterization (Not production tested).
48. For total analog system Idd < 5 mA, depending on package used. With higher total analog system currents it is recommended that the SAR ADC be used in differential mode.

11.5.9 Mixer

The mixer is created using a SC/CT analog block; see the Mixer component datasheet in PSoC Creator for full electrical specifications and APIs.

Table 11-34. Mixer DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
V_{OS}	Input offset voltage	High power mode, V_{IN} = 1.024 V, V_{REF} = 1.024 V	–	–	15	mV
	Quiescent current		–	0.9	2	mA
G	Gain		–	0	–	dB

Table 11-35. Mixer AC Specifications[59]

Parameter	Description	Conditions	Min	Typ	Max	Units
f_{LO}	Local oscillator frequency	Down mixer mode	–	–	4	MHz
f_{in}	Input signal frequency	Down mixer mode	–	–	14	MHz
f_{LO}	Local oscillator frequency	Up mixer mode	–	–	1	MHz
f_{in}	Input signal frequency	Up mixer mode	–	–	1	MHz
SR	Slew rate		3	–	–	V/µs

11.5.10 Transimpedance Amplifier

The TIA is created using a SC/CT analog block; see the TIA component datasheet in PSoC Creator for full electrical specifications and APIs.

Table 11-36. Transimpedance Amplifier (TIA) DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
V_{IOFF}	Input offset voltage		–	–	10	mV
Rconv	Conversion resistance[60]	R = 20K; 40 pF load	–25	–	+35	%
		R = 30K; 40 pF load	–25	–	+35	%
		R = 40K; 40 pF load	–25	–	+35	%
		R = 80K; 40 pF load	–25	–	+35	%
		R = 120K; 40 pF load	–25	–	+35	%
		R = 250K; 40 pF load	–25	–	+35	%
		R= 500K; 40 pF load	–25	–	+35	%
		R = 1M; 40 pF load	–25	–	+35	%
	Quiescent current[59]		–	1.1	2	mA

Table 11-37. Transimpedance Amplifier (TIA) AC Specifications[59]

Parameter	Description	Conditions	Min	Typ	Max	Units
BW	Input bandwidth (–3 dB)	R = 20K; –40 pF load	1200	–	–	kHz
		R = 120K; –40 pF load	240	–	–	kHz
		R = 1M; –40 pF load	25	–	–	kHz

Notes
59. Based on device characterization (Not production tested).
60. Conversion resistance values are not calibrated. Calibrated values and details about calibration are provided in PSoC Creator component datasheets. External precision resistors can also be used.

11.7 Memory

Specifications are valid for –40 °C ≤ T_A ≤ 105 °C and T_J ≤ 120 °C, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

11.7.1 Flash

Table 11-57. Flash DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
	Erase and program voltage	V_{DDD} pin	1.71	–	5.5	V

Table 11-58. Flash AC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
T_{WRITE}	Row write time (erase + program)		–	15	20	ms
T_{ERASE}	Row erase time		–	10	13	ms
	Row program time		–	5	7	ms
T_{BULK}	Bulk erase time (256 KB)		–	–	140	ms
	Sector erase time (16 KB)		–	–	15	ms
T_{PROG}	Total device programming time	No overhead[71]	–	5	7.5	seconds
	Flash data retention time, retention period measured from last erase cycle	Average ambient temp. T_A ≤ 55 °C, 100 K erase/program cycles	20	–	–	years
		Average ambient temp. T_A ≤ 85 °C, 10 K erase/program cycles	10	–	–	
		Ambient temp. T_A ≤ 105 °C, 10 K erase/program cycles, ≤ one year at T_A ≥ 75 °C [72]	10	–	–	

11.7.2 EEPROM

Table 11-59. EEPROM DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
	Erase and program voltage		1.71	–	5.5	V

Table 11-60. EEPROM AC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
T_{WRITE}	Single row erase/write cycle time		–	10	20	ms
	EEPROM data retention time, retention period measured from last erase cycle	Average ambient temp, T_A ≤ 25 °C, 1M erase/program cycles	20	–	–	years
		Average ambient temp, T_A ≤ 55 °C, 100 K erase/program cycles	20	–	–	
		Average ambient temp. T_A ≤ 85 °C, 10 K erase/program cycles	10	–	–	
		Ambient temp. T_A ≤ 105 °C, 10K erase/program cycles, ≤ one year at T_A ≥75 °C [72]	10	–	–	

Notes
71. See PSoC 5 Device Programming Specifications for a description of a low-overhead method of programming PSoC 5 flash.
72. Cypress provides a retention calculator to calculate the retention lifetime based on customers' individual temperature profiles for operation over the –40 °C to +105 °C ambient temperature range. Contact customercare@cypress.com.

11.8.3 Interrupt Controller

Table 11-71. Interrupt Controller AC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
	Delay from interrupt signal input to ISR code execution from main line code[80]		–	–	12	Tcy CPU
	Delay from interrupt signal input to ISR code execution from ISR code (tail-chaining)[80]		–	–	6	Tcy CPU

11.8.4 JTAG Interface

Figure 11-74. JTAG Interface Timing

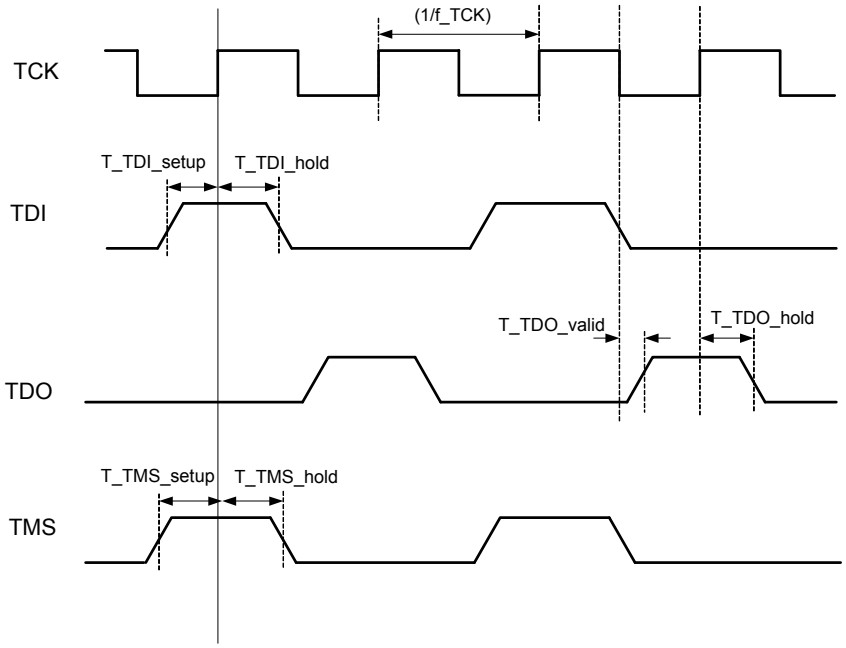


Table 11-72. JTAG Interface AC Specifications[81]

Parameter	Description	Conditions	Min	Typ	Max	Units
f_TCK	TCK frequency	3.3 V ≤ V_{DDD} ≤ 5 V	–	–	12[82]	MHz
		1.71 V ≤ V_{DDD} < 3.3 V	–	–	7[82]	MHz
T_TDI_setup	TDI setup before TCK high		(T/10) – 5	–	–	ns
T_TMS_setup	TMS setup before TCK high		T/4	–	–	
T_TDI_hold	TDI, TMS hold after TCK high	T = 1/f_TCK max	T/4	–	–	
T_TDO_valid	TCK low to TDO valid	T = 1/f_TCK max	–	–	2T/5	
T_TDO_hold	TDO hold after TCK high	T = 1/f_TCK max	T/4	–	–	
T_nTRST	Minimum nTRST pulse width	f_TCK = 2 MHz	8	–	–	ns

Notes
80. ARM Cortex-M3 NVIC spec. Visit www.arm.com for detailed documentation about the Cortex-M3 CPU.
81. Based on device characterization (Not production tested).
82. f_TCK must also be no more than 1/3 CPU clock frequency.

12. Ordering Information

In addition to the features listed in Table 12-1, every CY8C56LP device includes: up to 256K flash, 64K SRAM, 2K EEPROM, a precision on–chip voltage reference, precision oscillators, flash, ECC, DMA, a fixed function I^2C, JTAG/SWD programming and debug, external memory interface, boost, and more. In addition to these features, the flexible UDBs and analog subsection support a wide range of peripherals. To assist you in selecting the ideal part, PSoC Creator makes a part recommendation after you choose the components required by your application. All CY8C56LP derivatives incorporate device and flash security in user-selectable security levels; see the TRM for details.

Table 12-1. CY8C56LP Family with ARM Cortex-M3 CPU

Part Number	MCU Core				Analog							Digital				I/O[96]				Package	JTAG ID[97]
	CPU Speed (MHz)	Flash (KB)	SRAM (KB)	EEPROM (KB)	LCD Segment Drive	ADCs	DAC	Comparators	SC/CT Analog Blocks[94]	Opamps	DFB	CapSense	UDBs[95]	16-bit Timer/PWM	FS USB	CAN 2.0b	Total I/O	GPIO	SIO	USBIO		
CY8C5668AXI-LP010	67	256	64	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	72	62	8	2	100-TQFP	0x2E10A069
CY8C5668AXI-LP013	67	256	64	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	✔	72	62	8	2	100-TQFP	0x2E10D069
CY8C5668LTI-LP014	67	256	64	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	48	38	8	2	68-QFN	0x2E10E069
CY8C5667AXI-LP006	67	128	32	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	72	62	8	2	100-TQFP	0x2E106069
CY8C5667LTI-LP008	67	128	32	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	48	38	8	2	68-QFN	0x2E108069
CY8C5667LTI-LP009	67	128	32	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	✔	48	38	8	2	68-QFN	0x2E109069
CY8C5666AXI-LP001	67	64	16	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	20	4	–	–	70	62	8	0	100-TQFP	0x2E101069
CY8C5666AXI-LP004	67	64	16	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	20	4	✔	–	72	62	8	2	100-TQFP	0x2E104069
CY8C5666AXQ-LP004	67	64	16	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	20	4	✔	–	72	62	8	2	100-TQFP	0x2E104069
CY8C5666LTI-LP005	67	64	16	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	20	4	✔	–	48	38	8	2	68-QFN	0x2E105069
CY8C5667AXI-LP040	67	128	32	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	72	62	8	2	100-TQFP	0x2E128069
CY8C5667AXQ-LP040	67	128	32	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	72	62	8	2	100-TQFP	0x2E128069
CY8C5668AXI-LP034	67	256	64	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	72	62	8	2	100-TQFP	0x2E122069
CY8C5667LTI-LP041	67	128	32	2	✔	12-bit Del-Sig, 1x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	48	38	8	2	68-QFN	0x2E129069
CY8C5688AXI-LP099	80	256	64	2	4	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	✔	72	62	8	2	100-TQFP	0x2E163069
CY8C5688LTI-LP086	80	256	64	2	4	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	–	48	38	8	2	68-QFN	0x2E156069
CY8C5688FNI-LP211	80	256	64	2	✔	2x12-bit SAR	4	4	4	4	✔	✔	24	4	✔	✔	72	62	8	2	99-WLCSP	0x2E1D3069

Notes

94. Analog blocks support a wide variety of functionality including TIA, PGA, and mixers. See Example Peripherals on page 39 for more information on how analog blocks can be used.
95. UDBs support a wide variety of functionality including SPI, LIN, UART, timer, counter, PWM, PRS, and others. Individual functions may use a fraction of a UDB or multiple UDBs. Multiple functions can share a single UDB. See Example Peripherals on page 39 for more information on how UDBs can be used.
96. The I/O Count includes all types of digital I/O: GPIO, SIO, and the two USB I/O. See I/O System and Routing on page 32 for details on the functionality of each of these types of I/O.
97. The JTAG ID has three major fields. The most significant nibble (left digit) is the version, followed by a 2 byte part number and a 3 nibble manufacturer ID.

Document History Page

Description Title: PSoC® 5LP: CY8C56LP Family Datasheet Programmable System-on-Chip (PSoC®) Document Number: 001-84935				
Revision	**ECN**	**Orig. of Change**	**Submission Date**	**Description of Change**
**	3825653	MKEA	12/07/2012	Datasheet for new CY8C56LP family.
*A	3897878	MKEA	02/07/2013	Removed Preliminary status. Updated characterization footnotes in Electrical Specifications. Changed number of opamps in Ordering Information Updated conditions for SAR ADC INL and DNL specifications in Table 11-24 Updated Table 11-78 (ILO AC Specifications). Changed “UDB Configuration" to "UDB Working Registers” in Table 5-5. Removed references to CAN. Updated VIDAC INL spec.
*B	3902085	MKEA	02/12/2013	Changed Hibernate wakeup time from 125 µs to 200 µs in Table 6-3 and Table 11-3.
*C	3917994	MKEA	01/08/2013	Added Controller Area Network (CAN) content. Added CY8C5667AXI-LP040, CY8C5668AXI-LP034, and CY8C5667LTI-LP041 parts in Ordering Information.
*D	4114902	MKEA	09/30/2013	Added information about 1 KB cache in Features. Added warning on reset devices in the EEPROM section. Added DBGEN field in Table 5-3. Deleted statement about repeat start from the I^2C section. Removed T_{STG} spec from Table 11-1 and added a note clarifying the maximum storage temperature range. Updated chip Idd, regulator, opamp, delta-sigma ADC, SAR ADC, IDAC, and VDAC graphs. Added min and max values for the Regulator Output Capacitor parameter. Updated C_{IN} specs in GPIO DC Specifications and SIO DC Specifications. Updated rise and fall time specs in Fast Strong mode in Table 11-9, and deleted related graphs. Added I_{IB} parameter in Opamp DC Specifications Updated Vos spec conditions and changed TCVos max value from 0.55 to 1 in Table 11-20. Updated Voltage Reference Specifications and IMO AC Specifications. Updated F_{IMO} spec (3 MHz). Updated 100-TQFP package diagram. Added Appendix for CSP package (preliminary).
*E	4225729	MKEA	12/24/2013	Added SIO Comparator Specifications. Changed THIBERNATE wakeup spec from 200 to 150 µs. Updated CSP package details and ordering information. Added 80 MHz parts in Table 12-1.
*F	4386988	MKEA	05/22/2014	Updated General Description and Features. Added More Information and PSoC Creator sections. Updated JTAG IDs in Ordering Information. Updated 100-TQFP package diagram.
*G	4587100	MKEA	12/08/2014	Added link to AN72845 in Note 3. Updated interrupt priority numbers in *Section 4.4*. Updated *Section 5.4* to clarify the factory default values of EEPROM. Corrected ECCEN settings in Table 5-3. Updated *Section 6.1.1* and *Section 6.1.2*. Added a note below Figure 6-4. Updated Figure 6-12. Changed ‘Control Store RAM’ to ‘Dynamic Configuration RAM’ in Figure 7-4 and changed *Section 7.2.2.2* heading to ‘Dynamic Configuration RAM’. Updated *Section 7.8*.

Document History Page (continued)

Description Title: PSoC® 5LP: CY8C56LP Family Datasheet Programmable System-on-Chip (PSoC®) Document Number: 001-84935				
Revision	**ECN**	**Orig. of Change**	**Submission Date**	**Description of Change**
*H (cont.)	4698847	AVER / MKEA / GJV	03/24/2015	Updated Electrical Specifications: Updated Memory: Updated Flash: Updated Table 11-58: Updated details in “Conditions” column corresponding to “Flash data retention time” parameter. Added Note 72 and referred the same note in last condition corresponding to “Flash data retention time” parameter. Updated EEPROM: Updated Table 11-60: Updated details in “Conditions” column corresponding to “EEPROM data retention time” parameter. Added Note 72 and referred the same note in last condition corresponding to “EEPROM data retention time” parameter. Updated Nonvolatile Latches (NVL): Updated Table 11-62: Updated details in “Conditions” column corresponding to “NVL data retention time” parameter. Added Note 73 and referred the same note in last condition corresponding to “NVL data retention time” parameter. Updated Clocking: Updated Internal Main Oscillator: Updated Table 11-76: Replaced 85 °C with 105 °C. Updated Figure 11-78. Updated Ordering Information: Updated Part Numbering Conventions: Added “Q: Extended” as sub bullet under “g: Temperature Range”. Updated Packaging: Updated Table 13-1: Changed maximum value of T_A parameter from 85 °C to 105 °C. Changed maximum value of T_J parameter from 100 °C to 120 °C. Updated : Updated : spec 001-88034 – Changed revision from ** to *A.
*I	4839323	MKEA	07/15/2015	Added reference to code examples in More Information. Updated typ value of T_{WRITE} from 2 to 10 in EEPROM AC specs table. Changed “Device supply for USB operation" to "Device supply (V_{DDD}) for USB operation" in USB DC Specifications. Clarified power supply sequencing and margin for V_{DDA} and V_{DDD}. Updated Serial Wire Debug Interface with limitations of debugging on Port 15. Updated Delta-sigma ADC DC Specifications